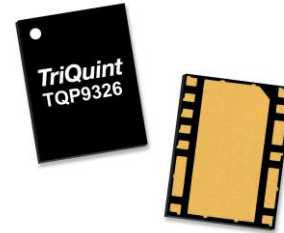


Applications

- Small-Cell / Pico-Cell
- Enterprise Femtocell
- Bands 7, 40, 41

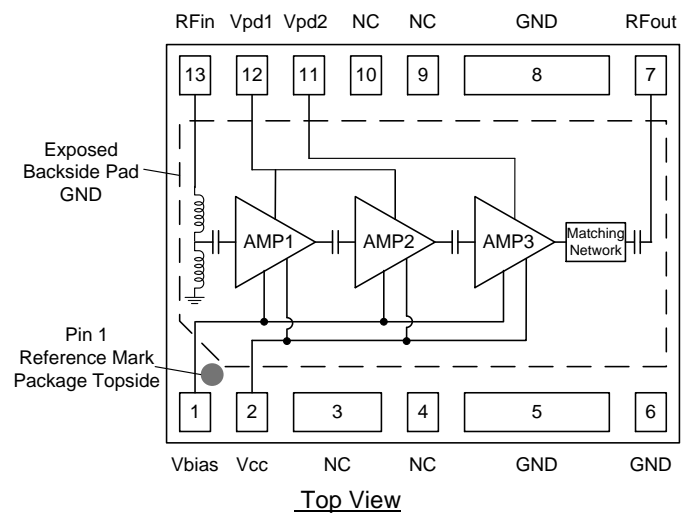
Product Features

- 2.3 – 2.7 GHz Frequency Range
- Fully integrated, 3 Stage Power Amplifier
- Internally matched 50 Ω input/output
- -50 dBc ACLR at +27 dBm Pavg (with correction)
- 34 dB Gain
- 22% PAE at +27 dBm
- 115 mA Quiescent Current
- In-built Control Bias and Temp. Comp Circuit
- Single Supply Voltage: +5 V
- Lead-free / RoHS compliant
- POE Capable



3.5 x 4.5 mm Leadless SMT Package

Functional Block Diagram



General Description

The TQP9326 is a high-efficiency three-stage power amplifier in a low-cost surface-mount package with on-chip bias control and temperature control circuits, suitable for small cell base station applications.

TQP9326 provides 34 dB gain and +27 dBm linear power with linearization correction over the 2.5–2.7 GHz frequency range for Bands 7, 40, and 41. With pre-distortion, the amplifier is able to achieve -50 dBc ACLR at +27 dBm output power using 20 MHz LTE signal.

The TQP9326 integrates three high performance amplifier stages onto a module to allow for a compact system design and requires very few external components for operation. The amplifier is bias adjustable allowing the amplifier's power consumption to be optimized. The TQP9326 is available in a lead-free/RoHS-compliant 3.5 x 4.5 mm surface mount package.

Pin Configuration

Pin No.	Label
1	V _{BIAS}
2	V _{CC}
3, 4, 9, 10	NC
5, 6, 8	GND
7	RF _{Out}
11	V _{PD2}
12	V _{PD1}
13	RF _{In}
Backside Paddle	RF/DC Ground

Ordering Information

Part No.	Description
TQP9326	High Efficiency 0.5 W Small Cell PA
TQP9326-PCB	2.5 – 2.7 GHz Evaluation board

Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	-55 to +150 °C
Supply Voltage (V _{CC})	+6 V
RF Input Power, CW, 50Ω, T=25°C	+10 dBm

Operation of this device outside the parameter ranges given above may cause permanent damage.

Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
V _{DD}	+4.75	+5	+5.25	V
T _{CASE}	-40	+25	+85	°C
T _j for >10 ⁶ hours MTTF			+175	°C

Notes: Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: V_{CC} = +5V, V_{pd} = +5V, Temp = +25°C.

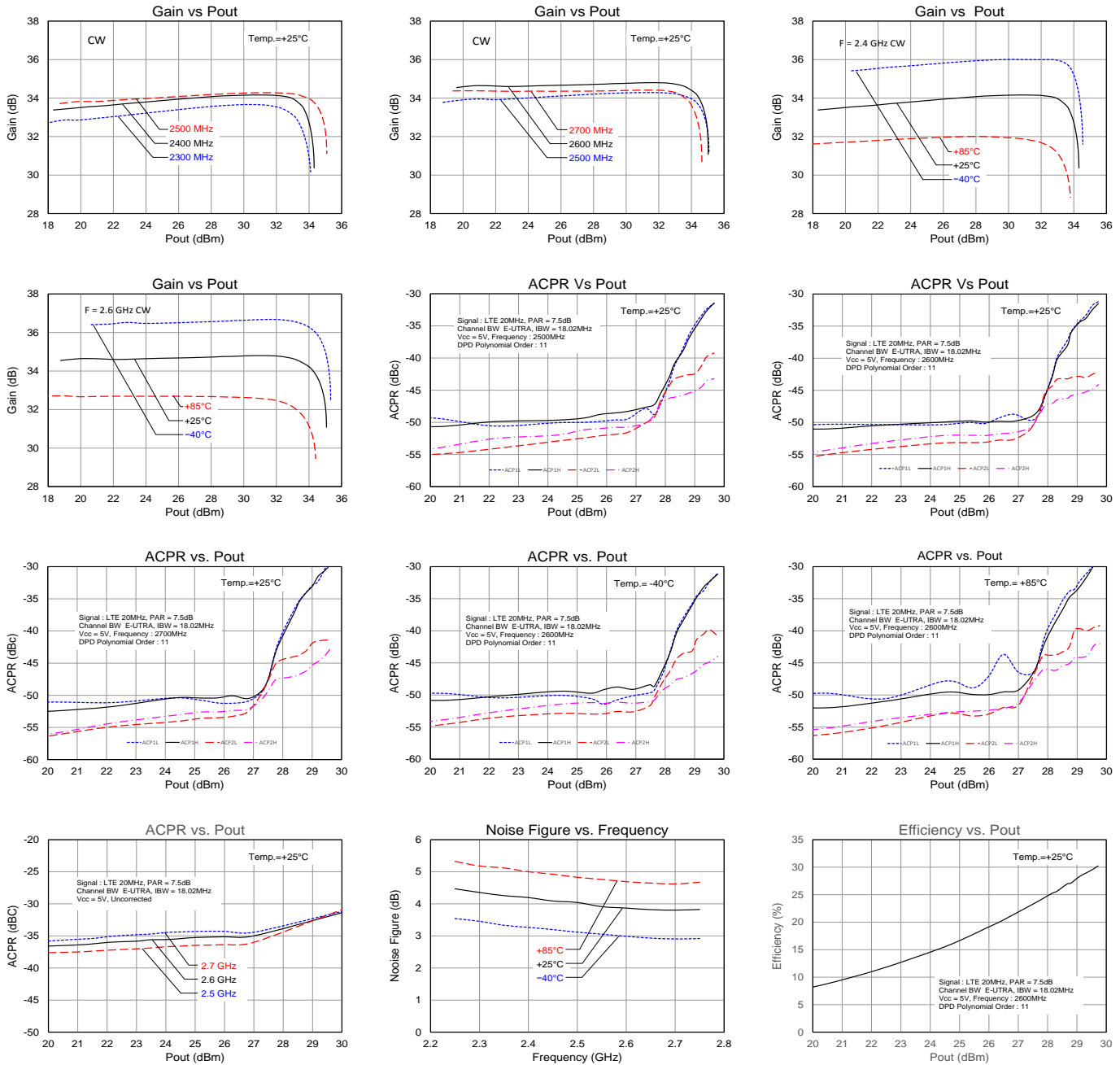
Parameter	Conditions	Min	Typ	Max	Units
Operational Frequency Range		2300		2700	MHz
Output Channel Power			+27		dBm
Gain	2500 – 2700 MHz		34		dB
ACLR Uncorrected	See note 1		-35		dBc
ACLR Corrected	See note 1		-48		dBc
Power Added Efficiency	See note 1		22		%
Noise Figure			4.0		dB
Output P3dB	2500-2700 MHz		+35		dBm
Supply Voltage			5		V
Quiescent Current, I _{CC}			115		mA
Reference Current, I _{pd}			2		mA
Operational Current, I _{CC}	P _{out} = +27 dBm		454		mA
VSWR Survivability	P _{out} = +26 dBm, 2.5 – 2.7 GHz Signal : WCDMA 1C, PAR = 8dB	7:1			
Thermal Resistance, θ _{JC}	Module (junction to case)		27		°C/W

Notes:

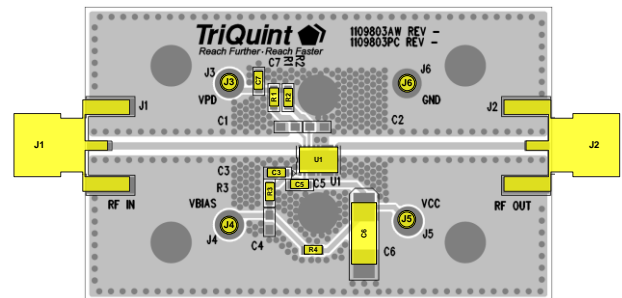
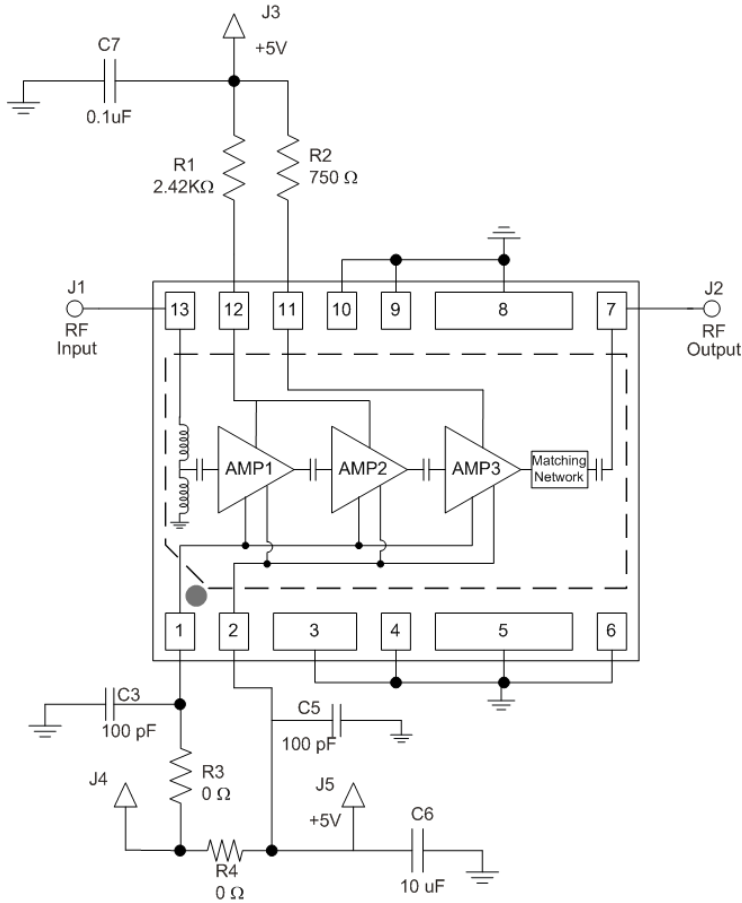
- Using LTE signal, 20 MHz/Carrier, IBW = 18.02 MHz, PAR 7.5 dB, P_{out} = +27 dBm

Performance Plots

Test conditions unless otherwise noted: $V_{CC} = +5\text{ V}$, $V_{PD1} = V_{PD2} = +5\text{ V}$, $Temp. = +25\text{ }^{\circ}\text{C}$.



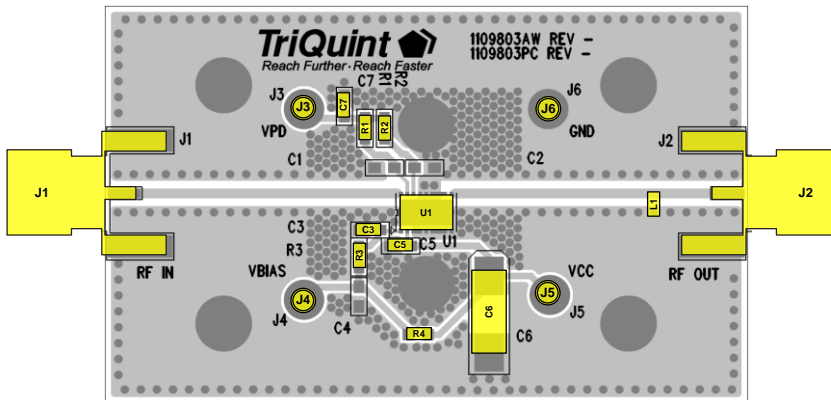
Application Circuit



Bill of Material

Ref Des	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board		
U1	n/a	High Efficiency 3-stage PA	TriQuint	TQP9326
R4	0 Ω	Resistor, Chip, 0603, 5%	various	
R3	0 Ω	Resistor, Chip, 0603, 1%	various	
C7	0.1 uF	Capacitor, Chip, 0603, 5%	various	
C6	10 uF	Capacitor, Chip, 6032, 10%, Tantalum	various	
C3, C5	100 pF	Capacitor, Chip, 0603, NPO/COG, 5%	various	
R2	750 Ω	Resistor, Chip, 0603, 5%, 1/16W	various	
R1	2.42 KΩ	Resistor, Chip, 0603, 5%, 1/16W	various	
C1, C2, C4		Do Not Place		

2.3 – 2.4 GHz Application Circuit



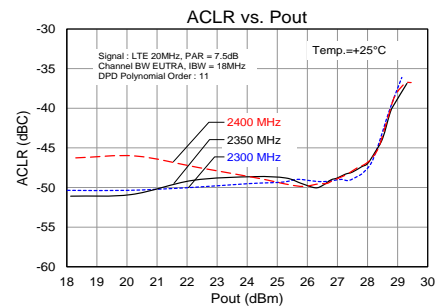
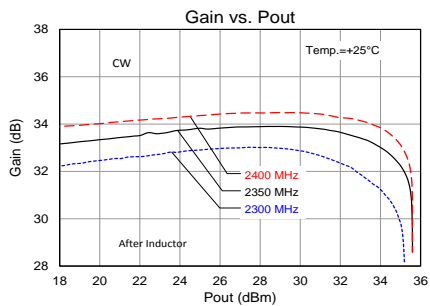
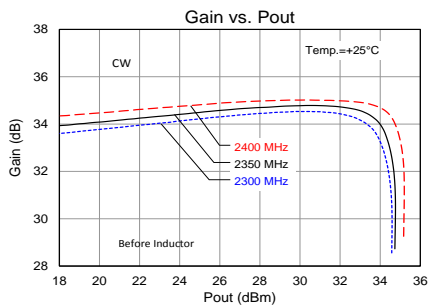
- Notes:
1. See Evaluation Board PCB Information section for PCB material and stack-up
 2. All components are of 0603 size unless otherwise specified.
 3. Critical component placement locations:
Distance from U1 Package (right edge) to L1 (left edge): 620 mils

Bill of Material (2.3 – 2.4 GHz Reference Design)

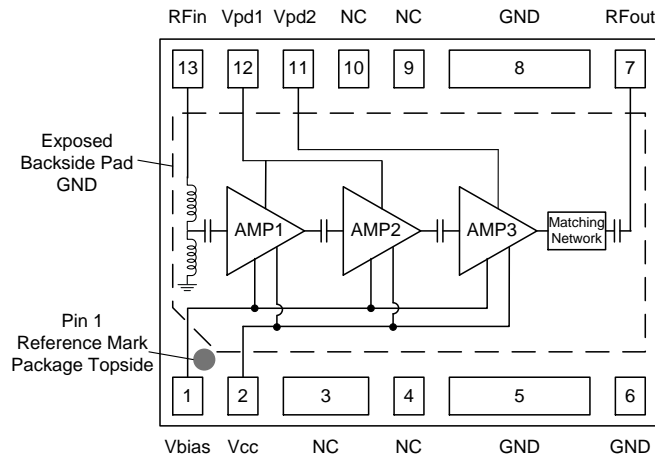
Ref Des	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board		
U1	n/a	High Efficiency 3-stage PA	TriQuint	TQP9326
R4	0 Ω	Resistor, Chip, 0603, 5%	various	
R3	0 Ω	Resistor, Chip, 0603, 1%	various	
C7	0.1 uF	Capacitor, Chip, 0603, 5%	various	
C6	10 uF	Capacitor, Chip, 6032, 10%, Tantalum	various	
C3, C5	100 pF	Capacitor, Chip, 0603, NPO/COG, 5%	various	
R2	750 Ω	Resistor, Chip, 0603, 5%, 1/16W	various	
R1	2.42 KΩ	Resistor, Chip, 0603, 5%, 1/16W	various	
L1	3.3 nH	Inductor, Chip, 0603, 5%	various	
C1, C2, C4		Do Not Place		

Performance Plots (2.3 – 2.4 GHz Reference Design)

Test conditions unless otherwise noted: $V_{CC} = +5V$, $V_{PD1} = V_{PD2} = +5V$, Temp. = +25°C.



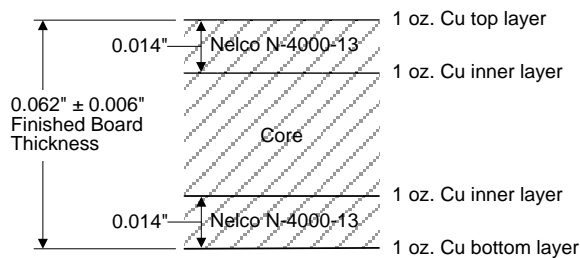
Pin Configuration and Description



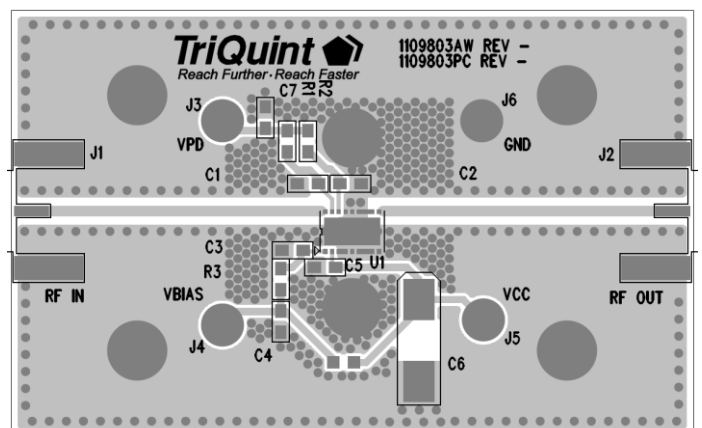
Pin No.	Label	Description
1	Vbias	Provides reference voltage for internal active biasing circuit
2	Vcc	DC voltage supply connection
3, 4, 9, 10	NC	No internal connection. Provide grounded land pads for PCB mounting integrity (Pins 5, 6, and 8 are internally grounded).
5, 6, 8	GND	Pins 5, 6, and 8 are internally grounded.
7	RFout	RF output pin. The DC is internally blocked at this pin.
11	Vpd2	Power down for Amp 1. This voltage adjusts for the current draw in Amp 1.
12	Vpd1	Power down for Amp 2. This voltage adjusts for the current draw in Amp 2.
13	RFin	RF input pin. Any external DC needs to be blocked from this pin.
Backside Paddle	RF/DC GND	RF/DC ground. Use recommended via pattern to minimize inductance and thermal resistance; see PCB Mounting Pattern for suggested footprint.

Evaluation Board PCB Information

TriQuint PCB 1100415 Material and Stack-up



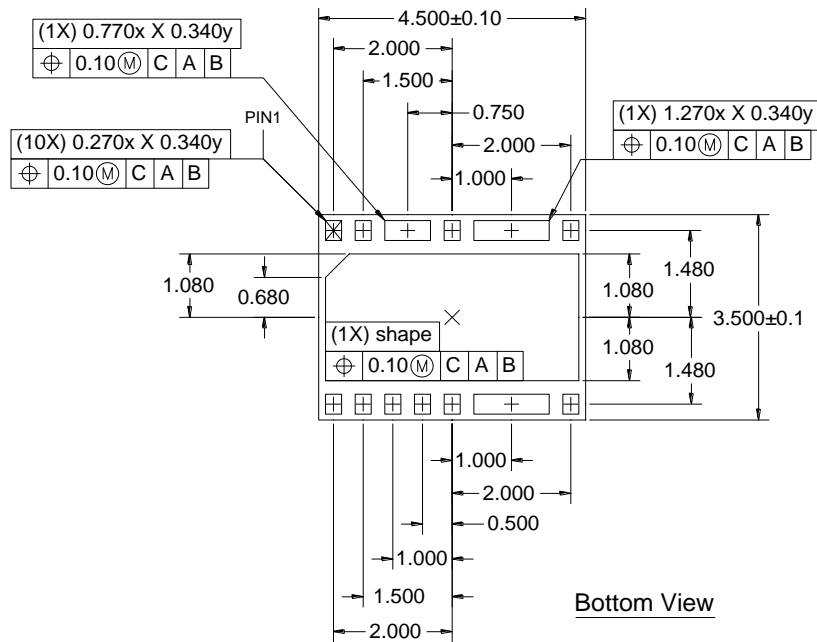
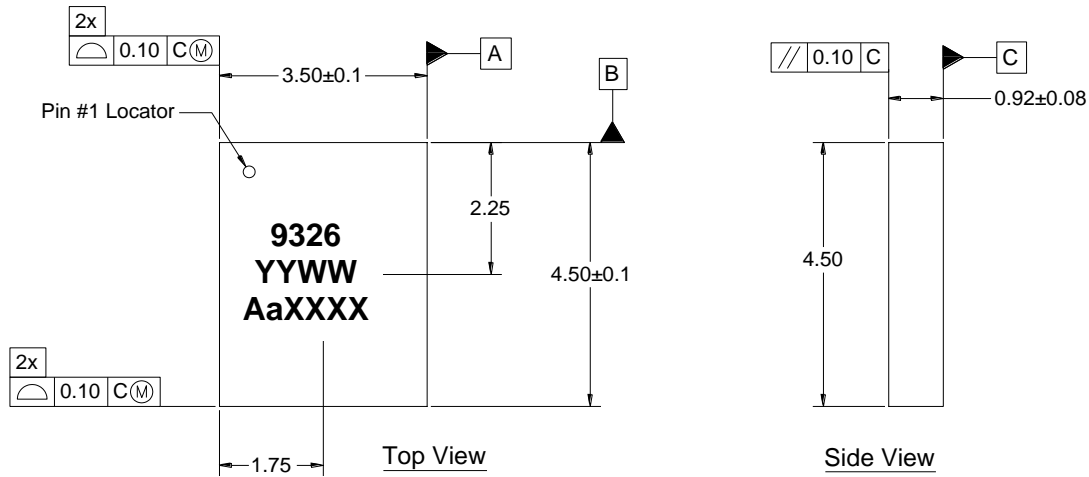
50 ohm line dimensions: width = .028"
spacing = .028".



Mechanical Information

Package Marking and Dimensions

Marking: Part number – 9326
 Assembly Code - YYWW
 Lot code –aaXXXX

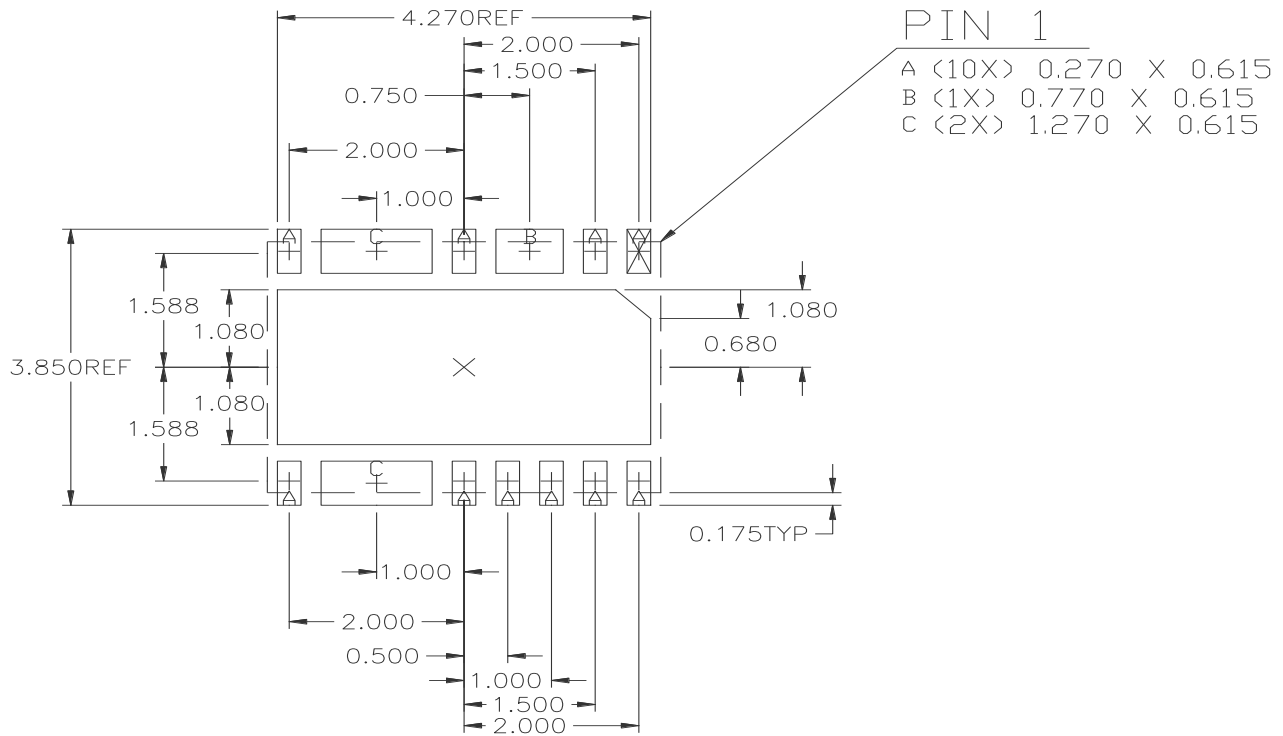


Notes:

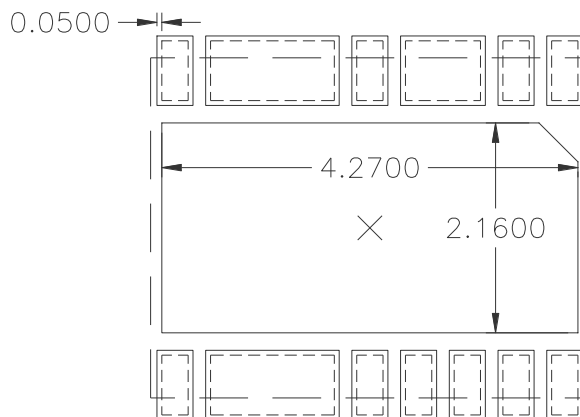
1. All dimensions are in millimeters. Angles are in degrees.
2. Except where noted, this part outline conforms to JEDEC standard MO-229.
3. Dimension and tolerance formats conform to ASME Y14.4M-1994.
4. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.

PCB Mounting Pattern

Recommend PCB land-pad metallization (Top View)



Recommended PCB solder mask opening (Top View)



Notes:

1. A heat sink underneath the area of the PCB for the mounted device is strictly required for proper thermal operation. Damage to the device can occur without the use of one.
2. Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm (.010").
3. Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.

Product Compliance Information

ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Class: 1C
Volt. Range: ≥ 1000 V to < 2000 V
Test: Human Body Model (HBM)
Standard: ESDA/JEDEC Standard JS-001-2012

ESD Class : C3
Volt. Range: ≥ 1000 V
Test: Charged Device Model (CDM)
Standard: JEDEC Standard JESD22-C101F

MSL Rating

MSL Rating: Level 3
Test: 260°C convection reflow
Standard: JEDEC Standard IPC/JEDEC J-STD-020

Solderability

Compatible with both lead-free (260 °C maximum reflow temperature) and tin/lead (245 °C maximum reflow temperature) soldering processes.

Contact plating: Electrolytic plated Au over Ni

RoHS Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.triquint.com Tel: 877-800-8584
Email: customer.support@qorvo.com

For information about the merger of RFMD and TriQuint as Qorvo:

Web: www.qorvo.com

For technical questions and application information:

Email: sjcappplications.engineering@qorvo.com

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